

National Semiconductor

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#### **DS36954**

### Quad Differential Bus Transceiver

#### **General Description**

The DS36954 is a low power, quad EIA-485 differential bus transceiver especially suited for high speed, parallel, multipoint, I/O bus applications. A compact 20-pin surface mount PLCC or SOIC package provides high transceiver integration and a very small PC board footprint.

Propagation delay skew between devices is specified to aid in parallel interface designs—limits on maximum and minimum delay times are guaranteed.

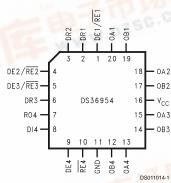
Five devices can implement a complete SCSI initiator or target interface. Three transceivers in a package are pinned out

for data bus connections. The fourth transceiver, with the flexibility provided by its individual enables, can serve as a control bus transceiver.

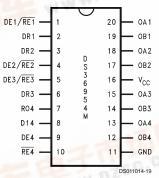
#### **Features**

- Pinout for SCSI interface
- Compact 20-pin PLCC or SOIC package
- Meets EIA-485 standard for multipoint bus transmission
- Greater than 60 mA source/sink currents
- Thermal shutdown protection
- Glitch-free driver outputs on power up and down

#### **Connection Diagrams**

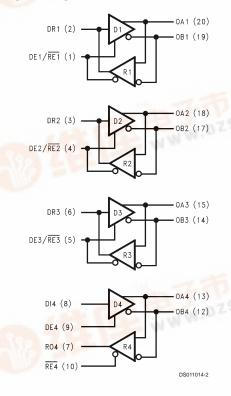


Order Number DS36954V See NS Package Number V20A



Order Number DS36954M See NS Package Number M20B

#### **Logic Diagrams**



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#### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 Supply Voltage
 7V

 Control Input Voltage
 V<sub>CC</sub> + 0.5V

 Driver Input Voltage
 V<sub>CC</sub> + 0.5V

 Driver Output Voltage/
 -10V to +15V

 Receiver Input Voltage
 5.5V

 Continuous Power Dissipation @ +25°C
 1.73W

 M Package
 1.73W

Derate M Package 13.7 mW/°C above +25°C Storage Temperature Range -65°C to +150°C Lead Temperature (Soldering 4 Sec.) 260°C

# Recommended Operating Conditions

	IVIIN	wax	Units
Supply Voltage, V <sub>CC</sub>	4.75	5.25	V
Bus Voltage	<b>-7</b>	+12	V
Operating Free Air			
Temperature (T <sub>A</sub> )	0	+70	°C

#### **Electrical Characteristics** (Note 2)

Derate V Package

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

13.9 mW/°C above +25°C

Symbol	Parameter	Condition	ns	Min	Тур	Max	Units
DRIVER	CHARACTERISTICS						
$V_{ODL}$	Differential Driver Output	I <sub>L</sub> = 60 mA		1.5	1.9		V
	Voltage (Full Load)	$V_{CM} = 0V$					
V <sub>OD</sub>	Differential Driver Output	$R_{L} = 100\Omega \text{ (EIA-422)}$		2.0	2.25		V
	Voltage (Termination Load)	$R_{L} = 54\Omega \text{ (EIA-485)}$		1.5	2.0		V
ΔIVODI	Change in Magnitude of Driver	$R_L = 54 \text{ or } 100\Omega$					
	Differential Output Voltage for	(Note 4) (Figure 1)	(Note 4) (Figure 1)			0.2	V
	Complementary Output States	(EIA-422/485)					
V <sub>oc</sub>	Driver Common Mode	$R_L = 54\Omega$ (Figure 1 ) (EIA-	485)			3.0	V
	Output Voltage (Note 5)						
ΔΙΛΟΟΙ	Change in Magnitude of	(Note 4) (Figure 1)				0.2	V
	Common Mode Output Voltage	(EIA-422/485)					
V <sub>OH</sub>	Output Voltage High	I <sub>OH</sub> = -55 mA		2.7	3.2		V
V <sub>OL</sub>	Output Voltage Low	I <sub>OL</sub> = 55 mA			1.4	1.7	V
V <sub>IH</sub>	Input Voltage High			2.0			V
V <sub>IL</sub>	Input Voltage Low					0.8	V
V <sub>CL</sub>	Input Clamp Voltage	I <sub>CL</sub> = -18 mA				-1.5	V
I <sub>IH</sub>	Input High Current	V <sub>IN</sub> = 2.4V (Note 3)				20	μΑ
I <sub>IL</sub>	Input Low Current	V <sub>IN</sub> = 0.4V (Note 3)				-20	μΑ
I <sub>osc</sub>	Driver Short-Circuit	V <sub>O</sub> = -7V (EIA-485)			-130	-250	mA
	Output Current	V <sub>O</sub> = 0V (EIA-422)			-90	-150	mA
	(Note 9)	V <sub>O</sub> = +12V (EIA-485)			130	250	mA
RECEIVE	R CHARACTERISTICS						
I <sub>OSR</sub>	Short Circuit Output Current	V <sub>O</sub> = 0V (Note 9)		-15	-28	-75	mA
l <sub>oz</sub>	TRI-STATE® Output Current	V <sub>O</sub> = 0.4V to 2.4V				20	μΑ
V <sub>OH</sub>	Output Voltage High	$V_{ID} = 0.2V, I_{OH} = 0.4 \text{ mA}$		2.4	3.0		V
V <sub>OL</sub>	Output Voltage Low	$V_{ID} = -0.2V, I_{OL} = 4 \text{ mA}$			0.35	0.5	V
$V_{TH}$	Differential Input High	$V_{\rm O} = V_{\rm OH}, I_{\rm O} = -0.4 \text{ mA}$			0.03	0.2	V
	Threshold Voltage	(EIA-422/485)					
$V_{TL}$	Differential Input Low	$V_O = V_{OL}$ , $I_O = 4.0$ mA		-0.20	-0.03		V
	Threshold Voltage (Note 6)	(EIA-422/485)					
V <sub>HST</sub>	Hysteresis (Note 7)	V <sub>CM</sub> = 0V		35	60		mV
DRIVER	AND RECEIVER CHARACTERIST	ics					
V <sub>IH</sub>	Enable Input Voltage High			2.0			V
V <sub>IL</sub>	Enable Input Voltage Low					0.8	V

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#### Electrical Characteristics (Note 2) (Continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Condi	tions	Min	Тур	Max	Units
DRIVER AND RECEIVER CHARACTERISTICS							
V <sub>CL</sub>	Enable Input Clamp Voltage	I <sub>CL</sub> = -18 mA				-1.5	V
I <sub>IN</sub>	Line Input Current	Other Input = 0V	V <sub>I</sub> = +12V		0.5	1.0	mA
	(Note 8)	$DE/\overline{RE} = 0.8V$	V <sub>1</sub> = -7V		-0.45	-0.8	mA
		DE4 = 0.8V					
I <sub>ING</sub>	Line Input Current	Other Input = 0V	V <sub>I</sub> = +12V			1.0	mA
	(Note 8)	$DE/\overline{RE}$ and $DE4 = 2V$					
		V <sub>CC</sub> = 3.0V	V <sub>I</sub> = -7V			-0.8	mA
		T <sub>A</sub> = +25°C					
I <sub>IH</sub>	Enable Input	V <sub>IN</sub> = 2.4V	V <sub>CC</sub> = 3.0V		1	40	μA
	Current High	DE/RE	V <sub>CC</sub> = 4.75V		1		μA
			V <sub>CC</sub> = 5.25V		1	40	μA
		V <sub>IN</sub> = 2.4V	V <sub>CC</sub> = 3.0V		1	20	μA
		DE4 or RE4	V <sub>CC</sub> = 5.25V		1	20	μA
I <sub>IL</sub>	Enable Input	V <sub>IN</sub> = 0.8V	V <sub>CC</sub> = 3.0V		-6	-40	μA
	Current Low	DE/RE	V <sub>CC</sub> = 4.75V		-12		μA
			V <sub>CC</sub> = 5.25V		-14	-40	μA
		V <sub>IN</sub> = 0.8V	V <sub>CC</sub> = 3.0V		-3	-20	μA
		DE4 or RE4	V <sub>CC</sub> = 5.25V		-7	-20	μA
I <sub>CCD</sub>	Supply Current (Note 10)	No Load, DE/RE and DI	E4 = 2.0V		75	90	mA
I <sub>CCR</sub>	Supply Current (Note 10)	No Load, DE/RE and RI	<del>E4</del> = 0.8V		50	70	mA

**Switching Characteristics**Over Supply Voltage and Operating Temperature ranges, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DRIVER SINGLE-ENDED CHARACTERISTICS							
t <sub>PZH</sub>	Output Enable Time to High Level	$R_L = 110\Omega$	(Figure 5)		35	40	ns
t <sub>PZL</sub>	Output Enable Time to Low Level	]	(Figure 6)		25	40	ns
t <sub>PHZ</sub>	Output Disable Time to High Level	]	(Figure 5)		15	25	ns
t <sub>PLZ</sub>	Output Disable Time to Low Level		(Figure 6)		35	40	ns
DRIVER D	IFFERENTIAL CHARACTERISTICS						
t <sub>r</sub> , t <sub>f</sub>	Rise and Fall Time	$R_L = 54\Omega$			13	16	ns
t <sub>PLHD</sub>	Differential Propagation	C <sub>L</sub> = 50 pF		9	15	19	ns
t <sub>PHLD</sub>	Delays (Note 15)	$C_D = 15 pF$		9	12	19	ns
t <sub>SKD</sub>	t <sub>PLHD</sub> - t <sub>PHLD</sub>   Diff. Skew	(Figures 3, 4,	9)		3	6	ns
RECEIVER	CHARACTERISTICS			•			•
t <sub>PLHD</sub>	Differential Propagation Delays	C <sub>L</sub> = 15 pF		9	14	19	ns
t <sub>PHLD</sub>		V <sub>CM</sub> = 2.0V		9	13	19	ns
t <sub>SKD</sub>	t <sub>PLHD</sub> - t <sub>PHLD</sub>   Diff. Receiver Skew	(Figure 7)			1	3	ns
t <sub>PZH</sub>	Output Enable Time to High Level	C <sub>L</sub> = 15 pF			15	22	ns
t <sub>PZL</sub>	Output Enable Time to Low Level	(Figure 8)			20	30	ns
t <sub>PHZ</sub>	Output Disable Time from High Level	]			20	30	ns
t <sub>PLZ</sub>	Output Disable Time from Low Level	]			17	25	ns

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise speci-

Note 3:  $I_{IH}$  and  $I_{IL}$  include driver input current and receiver TRI-STATE leakage current on DR(1-3).

Note 4:  $\Delta$  IVODI and  $\Delta$  IVOCI are changes in magnitude of  $V_{OD}$  and  $V_{OC}$ , respectively, that occur when the input changes state.

#### **Switching Characteristics** (Continued)

Note 5: In EIA Standards EIA-422 and EIA-485, V<sub>OC</sub>, which is the average of the two output voltages with respect to ground, is called output offset voltage, V<sub>OS</sub>.

Note 6: Threshold parameter limits specified as an algebraic value rather than by magnitude.

Note 7: Hysteresis defined as  $V_{HST}$  =  $V_{TH} - V_{TL}$ .

Note 8: I<sub>IN</sub> includes the receiver input current and driver TRI-STATE leakage current.

Note 9: Short one output at a time.

Note 10: Total package supply current.

Note 11: All typicals are given for  $V_{CC}$  = 5.0V and  $T_A$  = +25°C.

#### **Parameter Measurement Information**

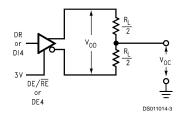


FIGURE 1. Driver  $V_{\text{OD}}$  and  $V_{\text{OC}}$  (Note 13)

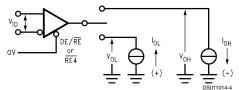


FIGURE 2. Receiver  $V_{OH}$  and  $V_{OL}$ 

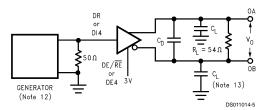


FIGURE 3. Driver Differential Propagation Delay Load Circuit

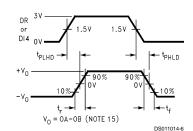
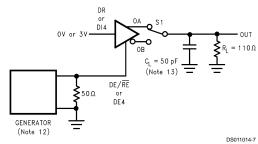


FIGURE 4. Driver Differential Propagation Delays and Transition Times



S1 to OA for DI = 3V S1 to OB for DI = 0V

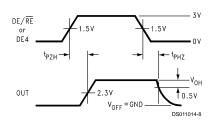


FIGURE 5. Driver Enable and Disable Timing (t $_{\rm PZH},\,t_{\rm PHZ}$ )

### Parameter Measurement Information (Continued)

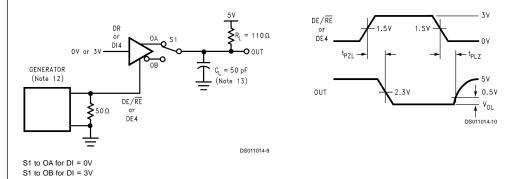


FIGURE 6. Driver Enable and Disable Timing ( $t_{\rm PZL},\,t_{\rm PLZ}$ )

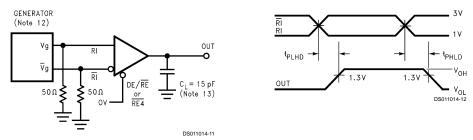


FIGURE 7. Receiver Differential Propagation Delay Timing

## Parameter Measurement Information (Continued)

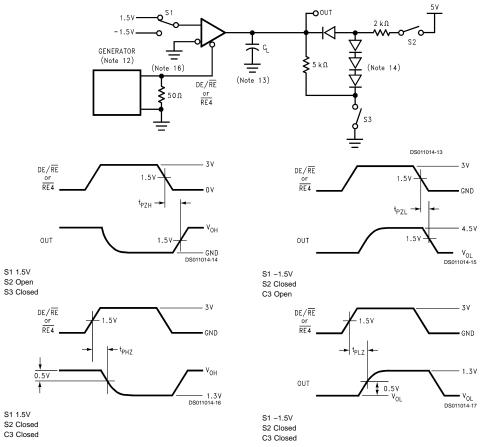
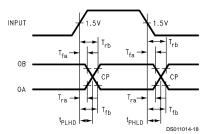


FIGURE 8. Receiver Enable and Disable Timing



$$T_{CP} = \frac{(T_{fb} \times T_{rb}) - (T_{ra} \times T_{fa})}{T_{rb} - T_{ra} - T_{fa} + T_{fb}}$$

 $T_{\rm ra}, T_{\rm rb}, T_{\rm fa}$  and  $T_{\rm fb}$  are propagation delay measurements to the 20% and 80% levels.  $T_{\rm CP}$  = Crossing Point

#### FIGURE 9. Propagation Delay Timing for Calculations of Driver Differential Propagation Delays

Note 12: The input pulse is supplied by a generator having the following characteristics: f = 1.0 MHz, 50% duty cycle,  $t_r$  and  $t_r < 6.0 \text{ ns}$ ,  $Z_Q = 50\Omega$ .

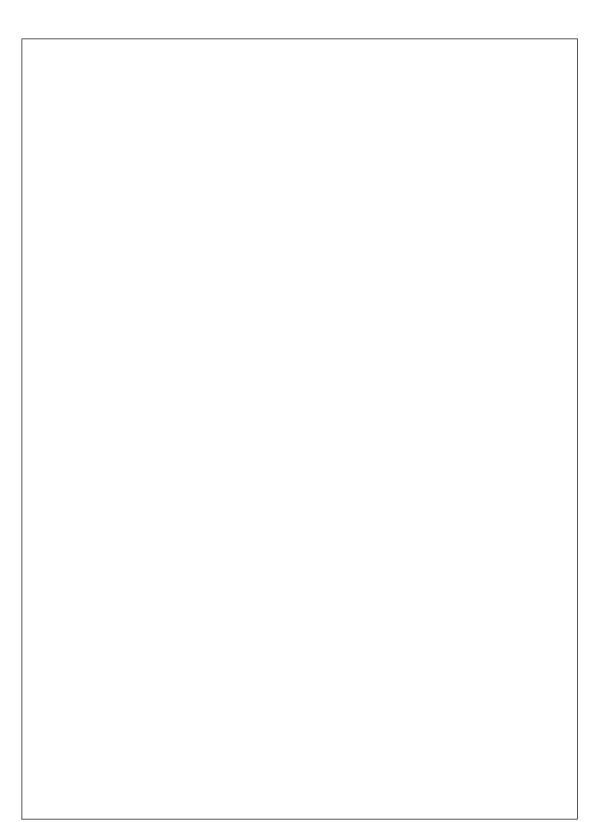
Note 13: C<sub>L</sub> includes probe and stray capacitance.

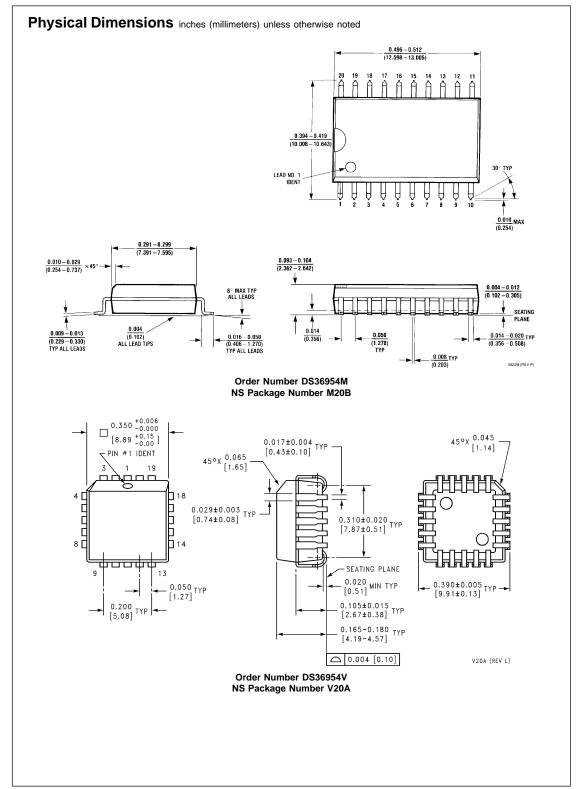
Note 14: Diodes are 1N916 or equivalent.

Note 15: Differential propagation delays are calculated from single-ended propagation delays measured from driver input to the 20% and 80% levels on the driver 6

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ote 16:	Parameter Measurement Information (Continued)  Note 16: On transceivers 1–3 the driver is loaded with receiver input conditions when DE/RE is high. Do not exceed the package power dissipation limit when						
sting.	on transcended 1 of the direct to readed with receiver input conditions which being it by high execution and package power disappation minit which						





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